



**MJD2955**  
**MJD3055**

## COMPLEMENTARY POWER TRANSISTORS

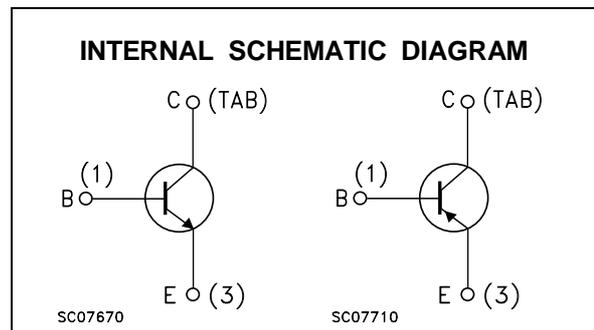
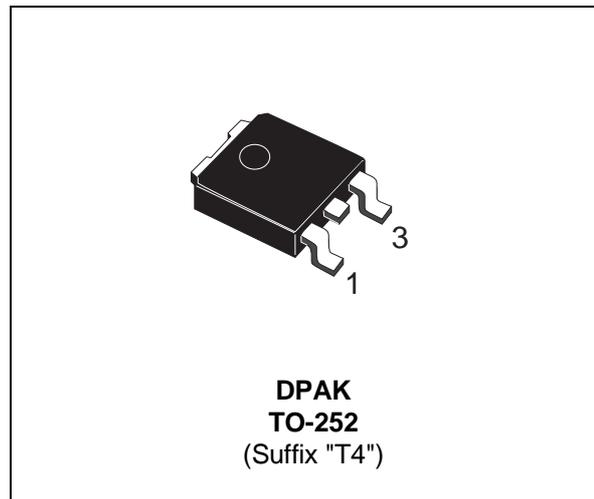
- STMicroelectronics PREFERRED SALESTYPES
- SURFACE-MOUNTING TO-252 (DPAK) POWER PACKAGE IN TAPE & REEL (SUFFIX "T4")
- ELECTRICALLY SIMILAR TO MJE2955T AND MJE3055T

### APPLICATIONS

- GENERAL PURPOSE SWITCHING AND AMPLIFIER

### DESCRIPTION

The MJD2955 and MJD3055 form complementary PNP-NPN pairs. They are manufactured using Epitaxial Base technology for cost-effective performance.



### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value		Unit
		NPN	MJD3055	
		PNP	MJD2955	
$V_{CBO}$	Collector-Base Voltage ( $I_E = 0$ )		70	V
$V_{CEO}$	Collector-Emitter Voltage ( $I_B = 0$ )		60	V
$V_{EBO}$	Emitter-Base Voltage ( $I_C = 0$ )		5	V
$I_C$	Collector Current		10	A
$I_B$	Base Current		6	A
$P_{tot}$	Total Dissipation at $T_c = 25^\circ\text{C}$		20	W
$T_{stg}$	Storage Temperature		-65 to 150	$^\circ\text{C}$
$T_j$	Max. Operating Junction Temperature		150	$^\circ\text{C}$

For PNP type voltage and current values are negative.

# MJD2955 / MJD3055

## THERMAL DATA

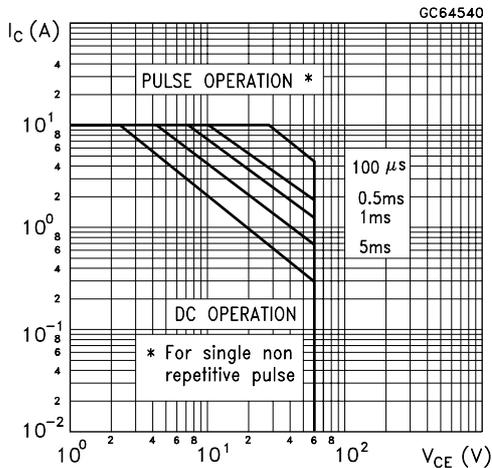
R <sub>thj-case</sub>	Thermal Resistance Junction-case	Max	6.25	°C/W
R <sub>thj-amb</sub>	Thermal Resistance Junction-ambient	Max	100	°C/W

## ELECTRICAL CHARACTERISTICS (T<sub>case</sub> = 25 °C unless otherwise specified)

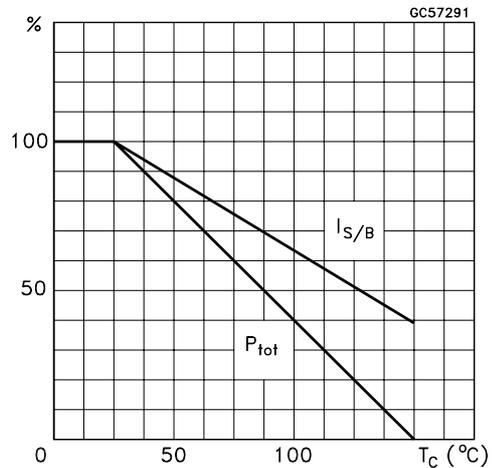
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I <sub>CEX</sub>	Collector Cut-off Current (V <sub>BE</sub> = -1.5 V)	V <sub>CE</sub> = 70 V V <sub>CE</sub> = 70 V T <sub>j</sub> = 150 °C			20 2	μA mA
I <sub>CBO</sub>	Collector Cut-off Current (I <sub>E</sub> = 0)	V <sub>CB</sub> = 70 V V <sub>CB</sub> = 70 V T <sub>j</sub> = 150 °C			20 2	μA mA
I <sub>CEO</sub>	Collector Cut-off Current (I <sub>B</sub> = 0)	V <sub>CE</sub> = 30 V			50	μA
I <sub>EBO</sub>	Emitter Cut-off Current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 5 V			0.5	mA
V <sub>CEO(sus)*</sub>	Collector-Emitter Sustaining Voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 30 mA	60			V
V <sub>CE(sat)*</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 4 A I <sub>B</sub> = 0.4 A I <sub>C</sub> = 10 A I <sub>B</sub> = 3.3 A			1.1 8	V V
V <sub>BE(on)*</sub>	Base-Emitter Voltage	I <sub>C</sub> = 4 A V <sub>CE</sub> = 4 V			1.8	V
h <sub>FE*</sub>	DC Current Gain	I <sub>C</sub> = 4 A V <sub>CE</sub> = 4 V I <sub>C</sub> = 10 A V <sub>CE</sub> = 4 V	20 5		100	
f <sub>T</sub>	Transition Frequency	I <sub>C</sub> = 0.5 A V <sub>CE</sub> = 10 V f = 500 KHz	2			MHz

\* Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %  
For PNP type voltage and current values are negative.

## Safe Operating Area



## Derating Curves



**TO-252 (DPAK) MECHANICAL DATA**

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	2.20		2.40	0.087		0.094
A1	0.90		1.10	0.035		0.043
A2	0.03		0.23	0.001		0.009
B	0.64		0.90	0.025		0.035
B2	5.20		5.40	0.204		0.213
C	0.45		0.60	0.018		0.024
C2	0.48		0.60	0.019		0.024
D	6.00		6.20	0.236		0.244
E	6.40		6.60	0.252		0.260
G	4.40		4.60	0.173		0.181
H	9.35		10.10	0.368		0.398
L2		0.8			0.031	
L4	0.60		1.00	0.024		0.039
V2	0°		8°	0°		0°

